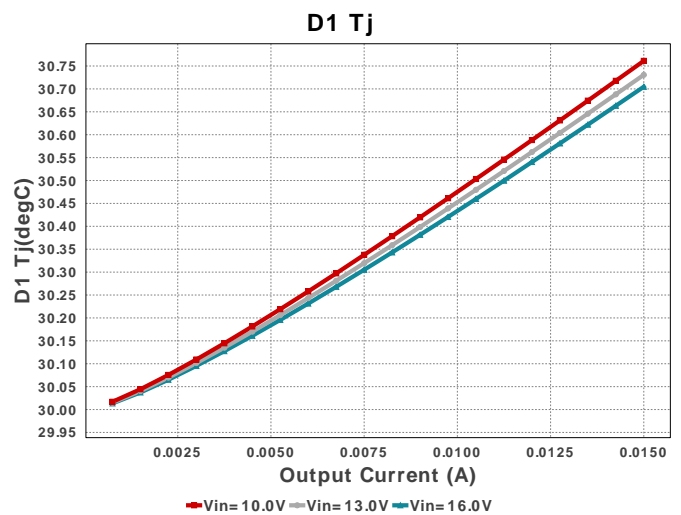
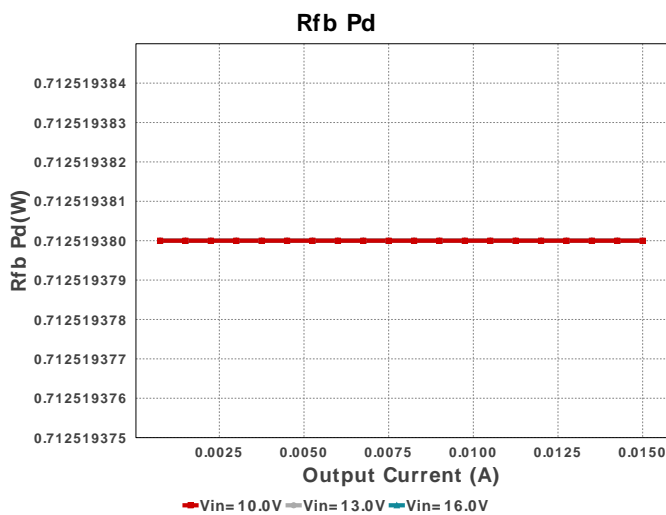
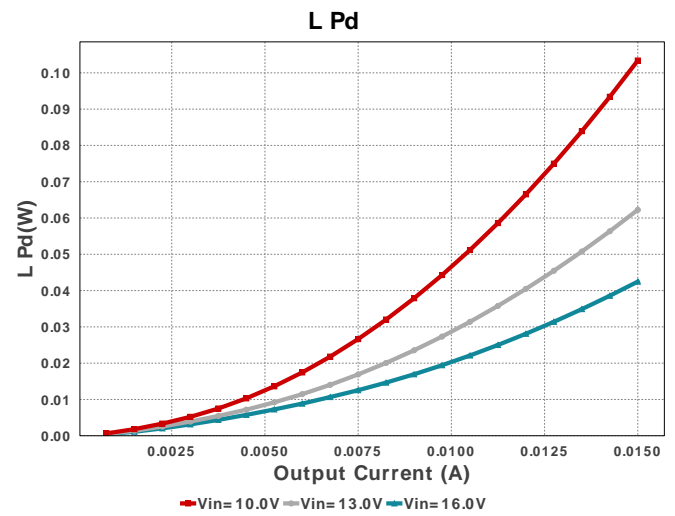
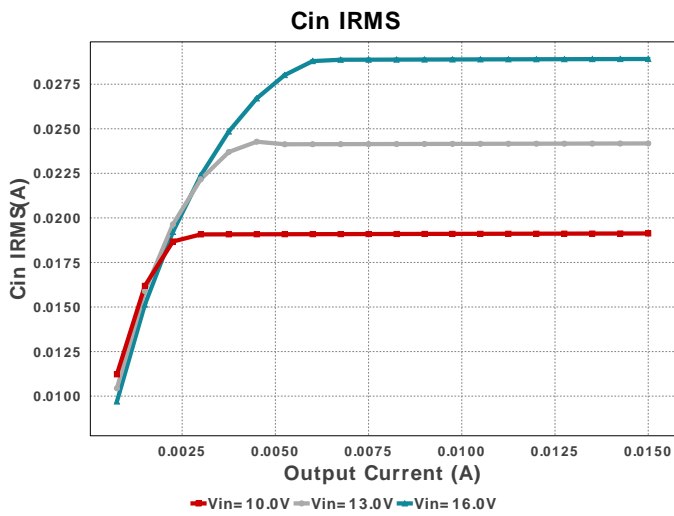
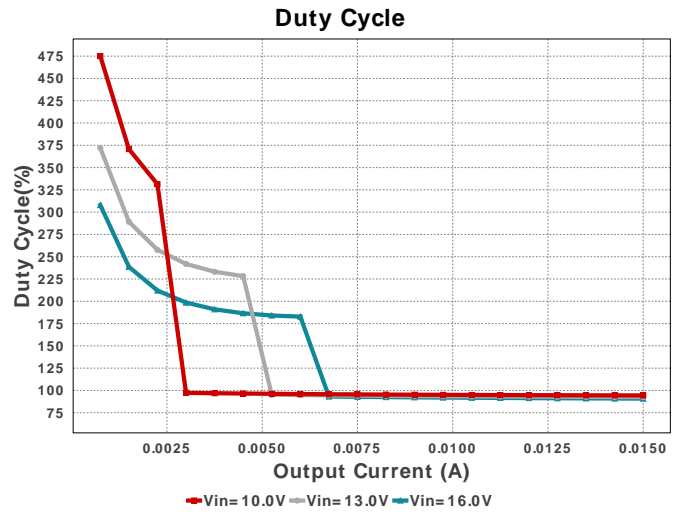
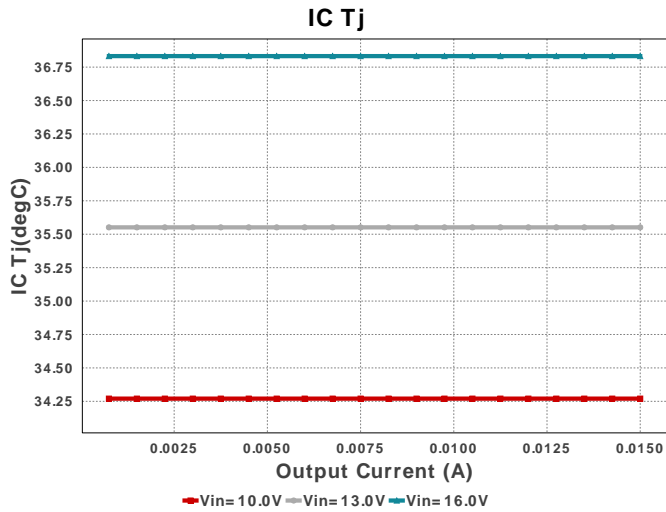
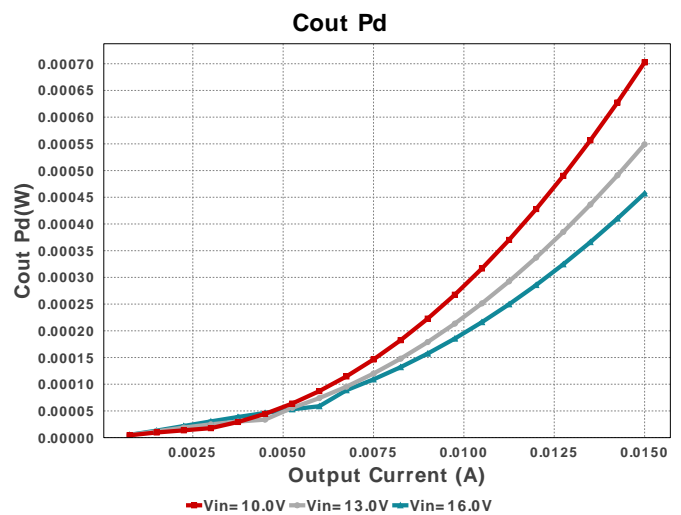
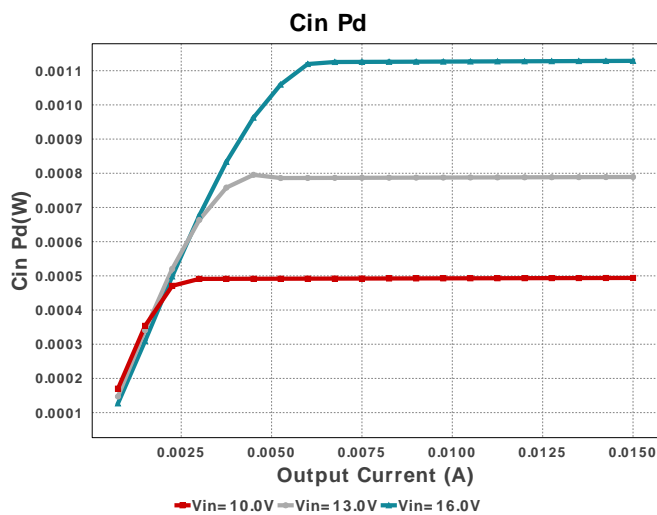
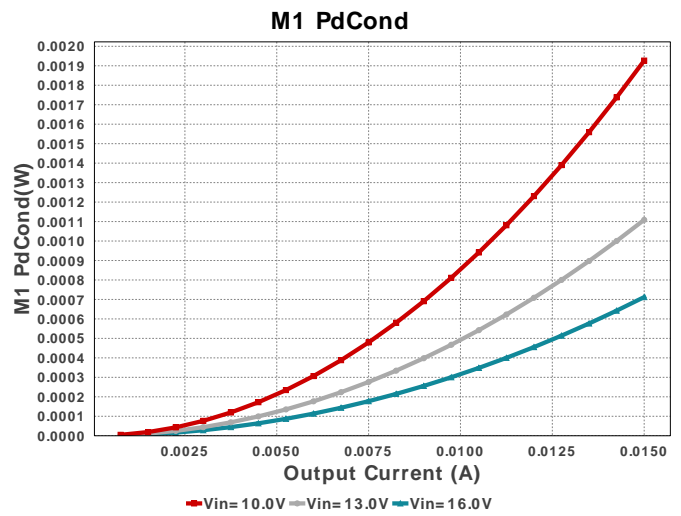
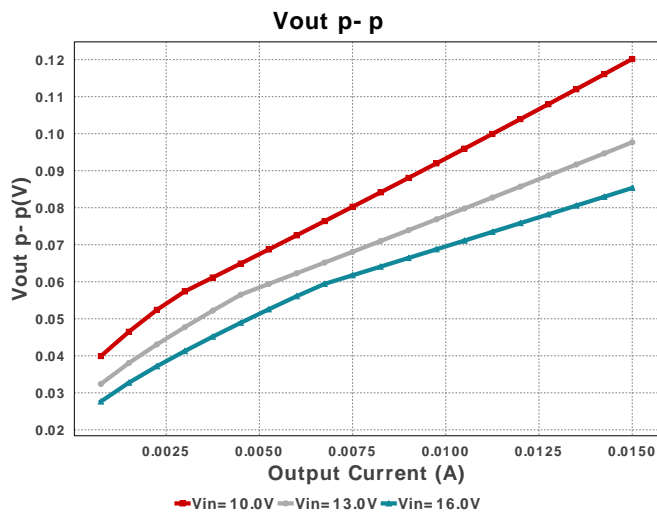
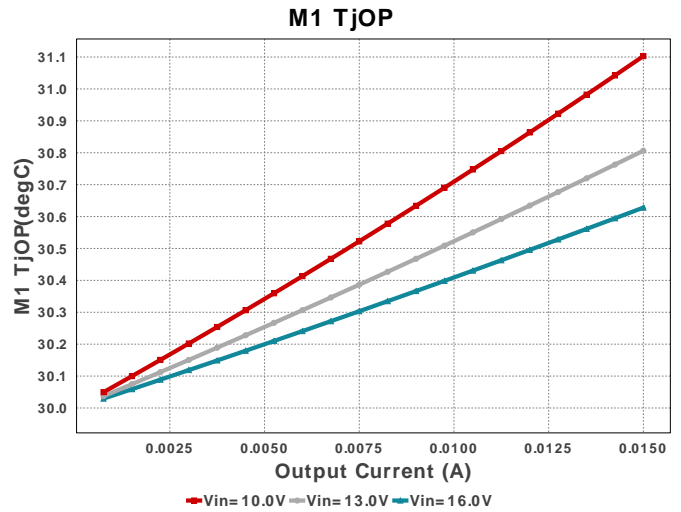
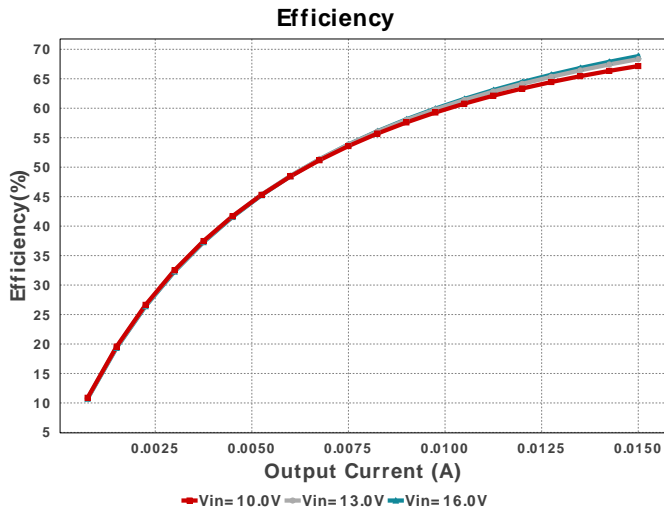


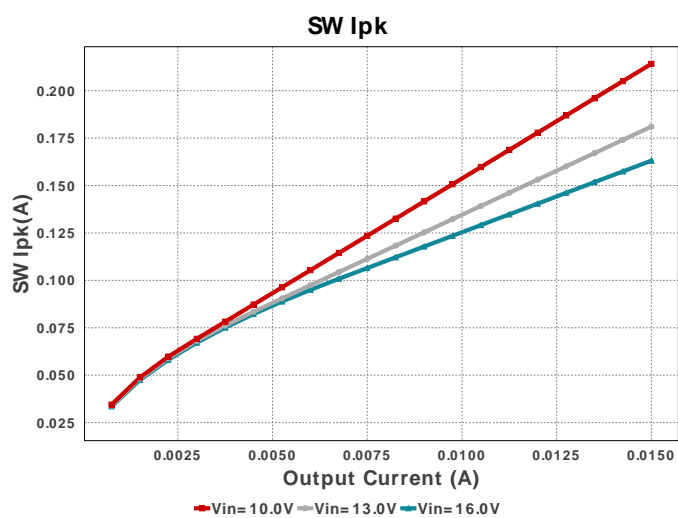
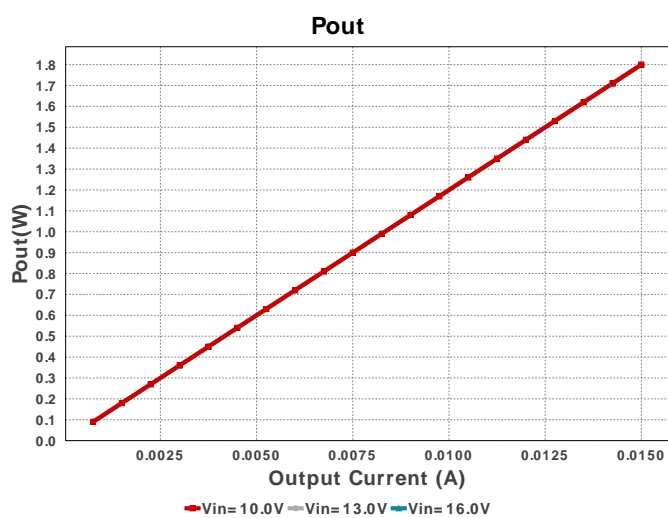
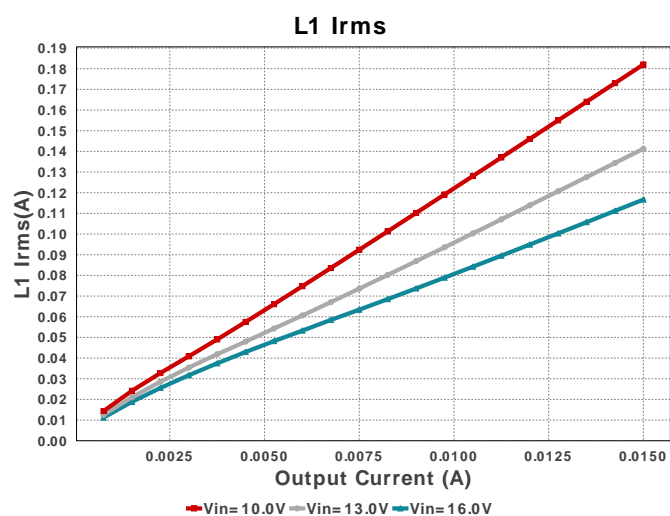
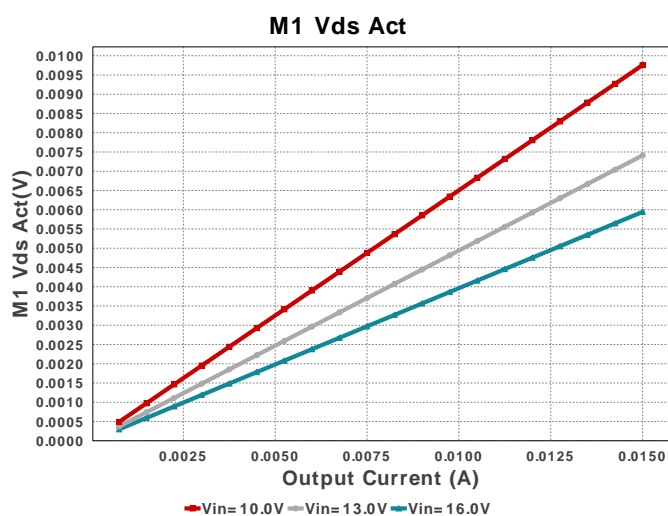
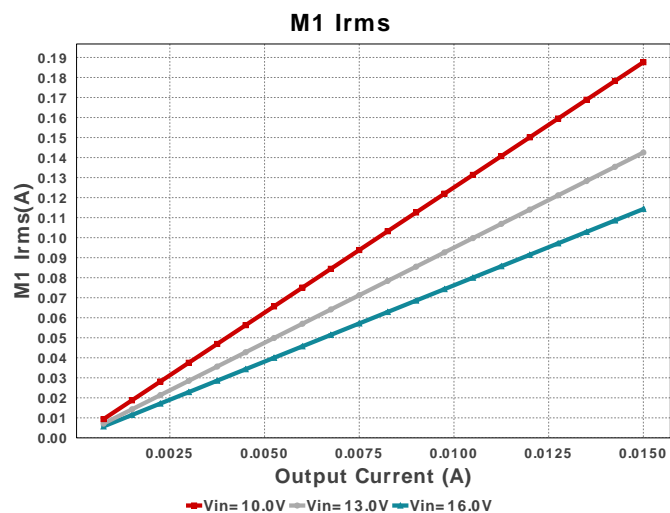
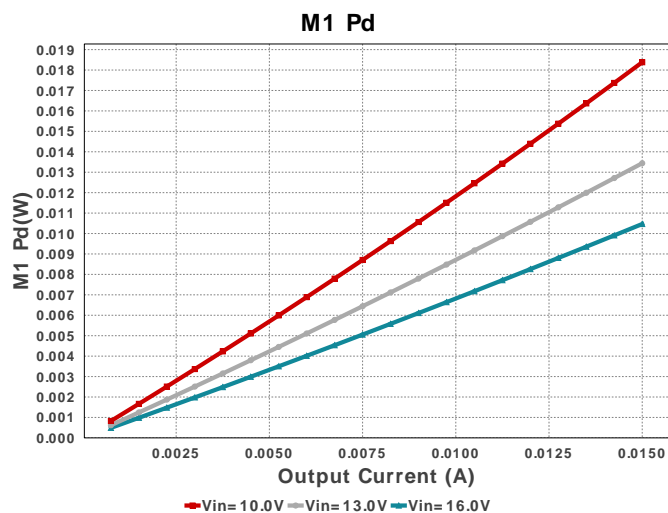


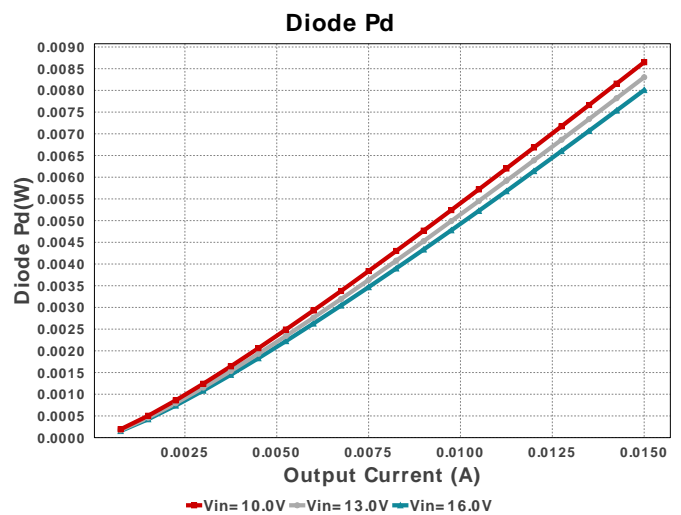
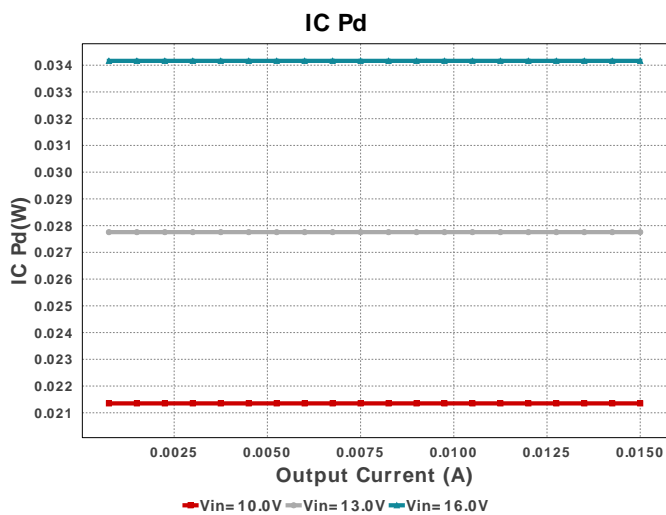
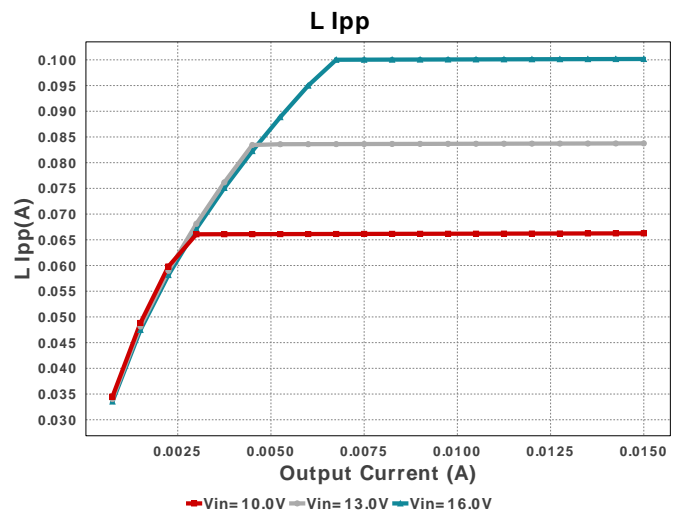
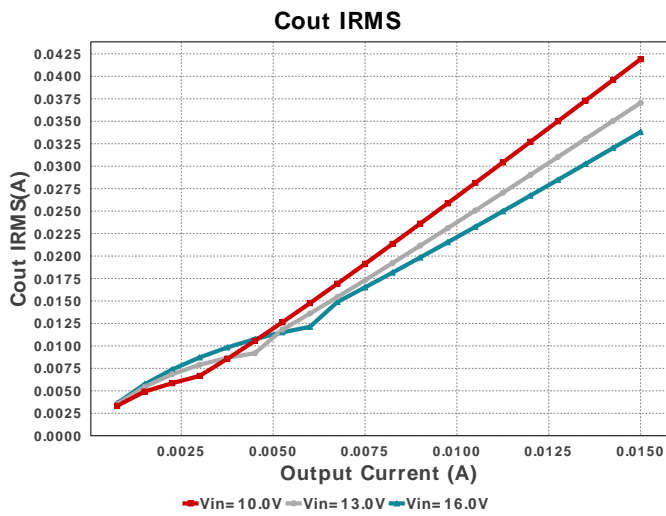
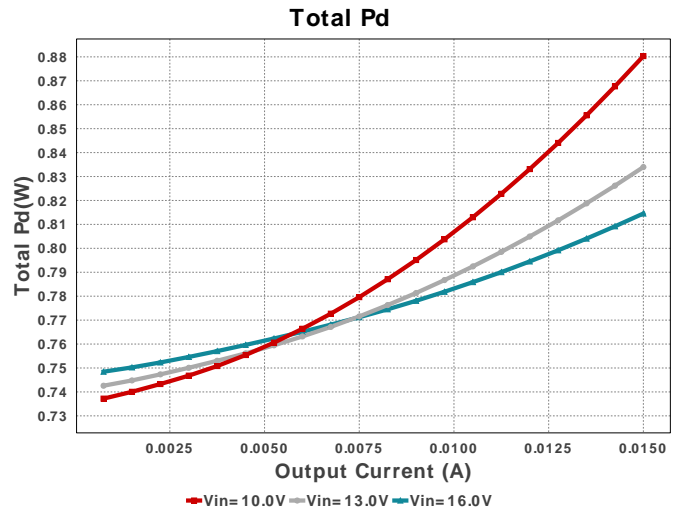
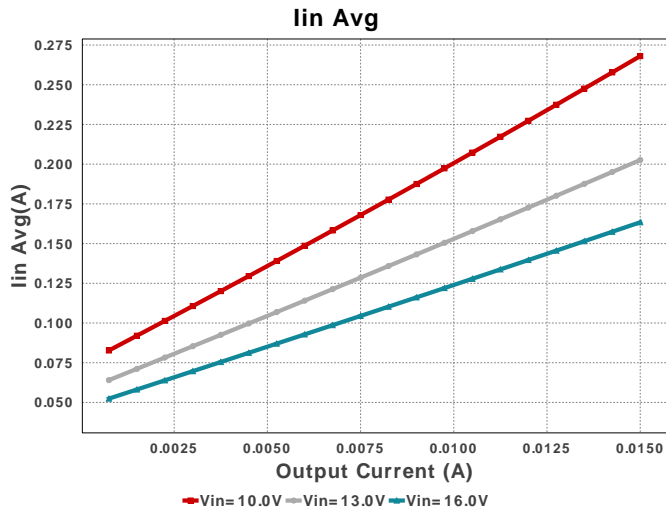
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Topology = Boost
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BOM Cost = \$5.49
BOM Count = 22
Total Pd = 0.88W

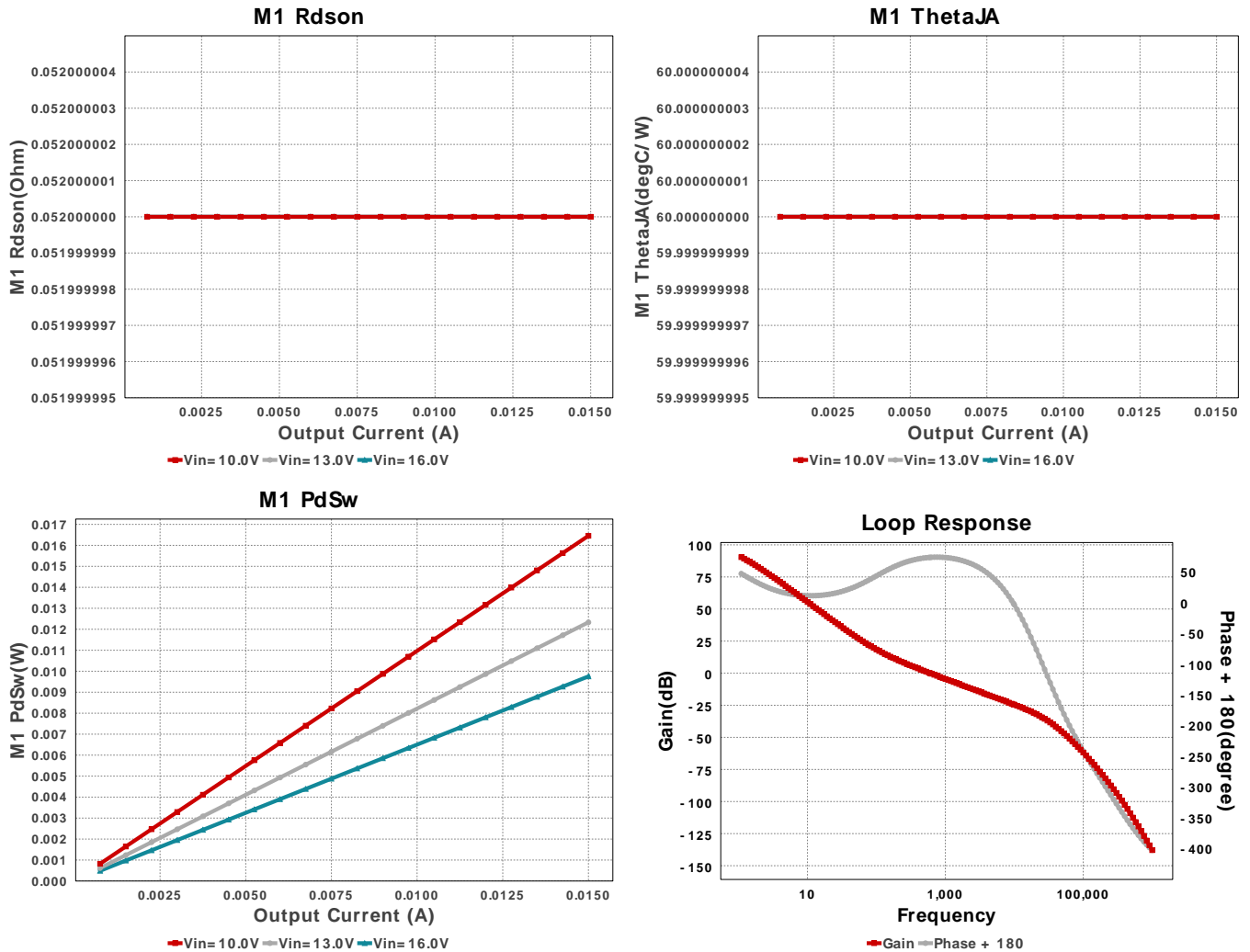
| # | Name | Manufacturer | Part Number | Properties | Qty | Price | Footprint |
|-----|-------|-----------------------|--------------------------------------|--|-----|--------|---|
| 8. | Cout1 | MuRata | GRM55DR72E105KW01L Series= X7R | Cap= 1.0 uF ESR= 7.086 mOhm VDC= 250.0 V IRMS= 2.0605 A | 1 | \$0.29 |  2220_200 54 mm ² |
| 9. | Css | MuRata | GRM155R71E822KA01D Series= X7R | Cap= 8.2 nF ESR= 1.0 mOhm VDC= 25.0 V IRMS= 0.0 A | 1 | \$0.01 |  0402 3 mm ² |
| 10. | D1 | SMC Diode Solutions | SK220ATR | VF@Io= 900.0 mV VRRM= 200.0 V | 1 | \$0.04 |  SMA 37 mm ² |
| 11. | L1 | Bourns | SDR1005-681KL | L= 680.0 uH DCR= 2.6 Ohm | 1 | \$0.29 |  SDR1005 176 mm ² |
| 12. | M1 | Infineon Technologies | BSZ520N15NS3 G | VdsMax= 150.0 V IdsMax= 21.0 Amps | 1 | \$0.55 |  PG-TSDSON-8 19 mm ² |
| 13. | Rcomp | Vishay-Dale | CRCW04025K90FKED Series= CRCW..e3 | Res= 5.9 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 |  0402 3 mm ² |
| 14. | Rfb1 | Vishay-Dale | CRCW0402210RFKED Series= CRCW..e3 | Res= 210.0 Ohm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 |  0402 3 mm ² |
| 15. | Rfb2 | Vishay-Dale | CRCW201020K0FKEF Series= CRCW..e3 | Res= 20.0 kOhm Power= 750.0 mW Tolerance= 1.0% | 1 | \$0.04 |  2010 32 mm ² |
| 16. | Rs1 | Vishay-Dale | CRCW0402102RFKED Series= CRCW..e3 | Res= 102.0 Ohm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 |  0402 3 mm ² |
| 17. | Rs2 | Vishay-Dale | CRCW04028K45FKED Series= CRCW..e3 | Res= 8.45 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 |  0402 3 mm ² |
| 18. | Rsns | Panasonic | ERJ-3RQFR22V Series= ERJ-3R | Res= 220.0 mOhm Power= 100.0 mW Tolerance= 1.0% | 1 | \$0.02 |  0603 5 mm ² |
| 19. | Rt | Vishay-Dale | CRCW040284K5FKED Series= CRCW..e3 | Res= 84.5 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 |  0402 3 mm ² |
| 20. | Ruv1 | Vishay-Dale | CRCW04021K87FKED Series= CRCW..e3 | Res= 1.87 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 |  0402 3 mm ² |
| 21. | Ruv2 | Vishay-Dale | CRCW040210K2FKED Series= CRCW..e3 | Res= 10.2 kOhm Power= 63.0 mW Tolerance= 1.0% | 1 | \$0.01 |  0402 3 mm ² |
| 22. | U1 | Texas Instruments | LM5022MM/NOPB | Switcher | 1 | \$0.90 |  MUB10A 24 mm ² |











Operating Values

| # | Name | Value | Category | Description |
|-----|---------------|-----------------------|----------|--|
| 1. | Cin IRMS | 19.497 mA | Current | Input capacitor RMS ripple current |
| 2. | Cout IRMS | 41.921 mA | Current | Output capacitor RMS ripple current |
| 3. | Iin Avg | 267.99 mA | Current | Average input current |
| 4. | L Ipp | 67.538 mA | Current | Peak-to-peak inductor ripple current |
| 5. | L1 Irms | 182.074 mA | Current | Inductor ripple current |
| 6. | M1 Irms | 187.256 mA | Current | M1 MOSFET Irms |
| 7. | SW Ipk | 214.796 mA | Current | Peak switch current |
| 8. | BOM Count | 22 | General | Total Design BOM count |
| 9. | FootPrint | 976.0 mm ² | General | Total Foot Print Area of BOM components |
| 10. | Frequency | 200.354 kHz | General | Switching frequency |
| 11. | IC Tolerance | 25.0 mV | General | IC Feedback Tolerance |
| 12. | M1 Rdson | 52.0 mOhm | General | Drain-Source On-resistance |
| 13. | M1 ThetaJA | 60.0 degC/W | General | MOSFET junction-to-ambient thermal resistance |
| 14. | Mode | CCM | General | Conduction Mode |
| 15. | Pout | 1.8 W | General | Total output power |
| 16. | Total BOM | \$5.49 | General | Total BOM Cost |
| 17. | D1 Tj | 30.761 degC | Op_Point | D1 junction temperature |
| 18. | Low Freq Gain | 86.124 dB | Op_Point | Gain at 1Hz |
| 19. | Vout Actual | 121.26 V | Op_Point | Vout Actual calculated based on selected voltage divider resistors |
| 20. | Vout OP | 120.0 V | Op_Point | Operational Output Voltage |
| 21. | Cross Freq | 375.655 Hz | Op_point | Bode plot crossover frequency |
| 22. | Duty Cycle | 94.387 % | Op_point | Duty cycle |
| 23. | Efficiency | 67.167 % | Op_point | Steady state efficiency |
| 24. | Gain Marg | -22.513 dB | Op_point | Bode Plot Gain Margin |
| 25. | IC Tj | 34.197 degC | Op_point | IC junction temperature |
| 26. | ICThetaJA | 200.0 degC/W | Op_point | IC junction-to-ambient thermal resistance |
| 27. | IOUT_OP | 15.0 mA | Op_point | Iout operating point |
| 28. | M1 TJOP | 31.094 degC | Op_point | M1 MOSFET junction temperature |
| 29. | Phase Marg | 69.452 deg | Op_point | Bode Plot Phase Margin |
| 30. | VIN_OP | 10.0 V | Op_point | Vin operating point |
| 31. | Vout p-p | 120.411 mV | Op_point | Peak-to-peak output ripple voltage |

| # | Name | Value | Category | Description |
|-----|----------------|-----------------|----------|--|
| 32. | Cin Pd | 513.162 μ W | Power | Input capacitor power dissipation |
| 33. | Cout Pd | 702.951 μ W | Power | Output capacitor power dissipation |
| 34. | Diode Pd | 8.65 mW | Power | Diode power dissipation |
| 35. | IC Pd | 20.984 mW | Power | IC power dissipation |
| 36. | L Pd | 103.43 mW | Power | Inductor power dissipation |
| 37. | M1 Pd | 18.239 mW | Power | M1 MOSFET total power dissipation |
| 38. | M1 PdCond | 1.918 mW | Power | M1 MOSFET conduction losses |
| 39. | M1 PdSw | 16.321 mW | Power | M1 MOSFET switching losses |
| 40. | Rfb Pd | 712.519 mW | Power | Rfb Power Dissipation |
| 41. | Total Pd | 879.892 mW | Power | Total Power Dissipation |
| 42. | M1 Vds Act | 9.737 mV | | M Vds |
| 43. | Vout Tolerance | 4.023 % | | Vout Tolerance based on IC Tolerance (no load) and voltage divider resistors if applicable |

Design Inputs

| # | Name | Value | Description |
|----|---------|--------|------------------------|
| 1. | Iout | 15.0 m | Maximum Output Current |
| 2. | VinMax | 16.0 | Maximum input voltage |
| 3. | VinMin | 10.0 | Minimum input voltage |
| 4. | Vout | 120.0 | Output Voltage |
| 5. | base_pn | LM5022 | Base Product Number |
| 6. | source | DC | Input Source Type |
| 7. | Ta | 30.0 | Ambient temperature |

Design Assistance

1. **LM5022** Product Folder : <http://www.ti.com/product/LM5022> : contains the data sheet and other resources.

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